

## Certificate of Analysis (CoA)

Dec. 25, 2025

**Product Name:** Aluminum-doped Zinc Oxide (AZO) Sputtering Target**Chemical Formula:**  $\text{ZnO}:\text{Al}_2\text{O}_3$ **Composition:** 97 wt% ZnO / 3 wt%  $\text{Al}_2\text{O}_3$ **Purity:** 99.99% (4N, oxide basis)**Dimensions:**  $\varnothing 76.2 \text{ mm} \times 1.59 \text{ mm}$ **Bonding:** Indium-bonded to Copper (Cu) Backing Plate, 1.59 mm thick**Lot Number:** CSFM-251225085TB**Quantity:** 1 piece**Manufactured by:** Thin-Film Materials

### Physical Description

- Form: Oxide ceramic sputtering target, bonded
- Appearance: Off-white to light gray, dense ceramic
- Crystal Structure: Hexagonal wurtzite (ZnO structure with Al doping)
- Theoretical Density:  $\sim 5.6 \text{ g/cm}^3$
- Resistivity:  $< 1.0 \times 10^{-3} \Omega \cdot \text{cm}$  (for sintered target)
- Fabrication: Powder synthesis, pressing, sintering, precision grinding, and bonding

### Total Impurities (by ICP-OES / GDMS)

Element	Symbol	Max. Content (ppm)
<b>ZnO, <math>\text{Al}_2\text{O}_3</math></b>	<b>Zn, Al</b>	<b>Balance (&gt;99.99%)</b>
Iron	Fe	< 5
Silicon	Si	< 5
Copper	Cu	< 5
Lead	Pb	< 5
Nickel	Ni	< 5

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Element	Symbol	Max. Content (ppm)
Sodium	Na	< 5
<b>Other Metallic (each)</b>	-	< 2

**Handling & Storage**

- This is a brittle ceramic material. Handle with care to avoid chipping or cracking.
- Store in a dry, clean environment to prevent moisture absorption and contamination.
- Avoid thermal shock.

**Declaration**

We certify that this AZO target meets the specified doping concentration and 4N purity, providing a reliable source for depositing transparent conductive oxide (TCO) thin films in cost-effective photovoltaic, display, and low-emissivity coating applications.

**Authorized Signature:**Inspection Certificate by: Nancy LiuApprover by: Chen Qiang